

SILICON POWER TRANSISTORS 2SA1069, 1069A

PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SA1069/1069A are the mold power transistors developed for <R> ORDERING INFORMATION high-speed switching, and is ideal for use as a driver in devices such as switching regulators, DC/DC converters, and high-frequency power amplifiers.

Part No.	Package
2SA1069	TO-220AB
2SA1069A	(MP-25)
2SA1069-Z	TO-220SMD
2SA1069A-Z	(MP-25Z)

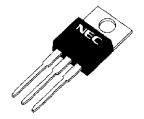
FEATURES

- · Low collector saturation voltage
- · Fast switching speed

(TO-220AB)

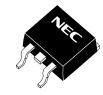
ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	Vcво		-80	V
Collector to emitter voltage	VCEO		-60/-80	V
Emitter to base voltage	VEBO		-12	٧
Collector current (DC)	Ic(DC)		-5.0	Α
Collector current (pulse)	I _{C(pulse)}	PW ≤ 300 <i>μ</i> s, duty cycle ≤ 10%	-10	Α
Base current (DC)	I _{B(DC)}		-2.5	Α
Total power dissipation	Рт	Tc = 25°C	30	W
		T _A = 25°C	1.5	W
Junction temperature	Tj		150	°C
Storage temperature	T _{stg}		-55 to +150	°C



(TO-220SMD)

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ELECTRICAL CHARACTERISTICS (TA = 25°C)

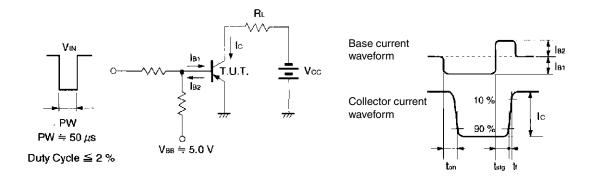
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	$Ic = -3.0 \text{ V}, I_{B1} = -0.3 \text{ A}, L = 1 \text{ mH}$	-60/-80			V
Collector to emitter voltage	VCEX(SUS)1	Ic = -3.0 A, Ib ₁ = $-I$ B ₂ = -0.3 A, VBE(OFF) = 5.0 V, L = 180 μ H, clamped	-60/-80			V
Collector to emitter voltage	VCEX(SUS)2	Ic = -6.0 A, I _{B1} = -0.6 A, I _{B2} = 0.3 A, $V_{BE(OFF)} = 5.0 \text{ V}$, L = 180 μH , clamped	-60/-80			V
Collector cutoff current	Ісво	$V_{CB} = -60/-80 \text{ V}, I_E = 0 \text{ A}$			-10	μΑ
Collector cutoff current	ICER	$V_{\text{CE}} = -60/-80 \text{ V}, \text{ R}_{\text{BE}} = 51 \ \Omega, \text{ Ta} = 125 \ ^{\circ}\text{C}$			-1.0	mA
Collector cutoff current	ICEX1	$V_{CE} = -60/-80 \text{ V}, V_{BE(OFF)} = 1.5 \text{ V}$			-10	μ A
Collector cutoff current	ICEX2	$V_{CE} = -60/-80 \text{ V}, V_{BE(OFF)} = 1.5 \text{ V},$ $T_A = 125 ^{\circ}\text{C}$			-1.0	mA
Emitter cutoff current	І ЕВО	V _{EB} = -5.0 V, I _C = 0 A			-10	μΑ
DC current gain	h _{FE1}	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -0.3 \text{ A}^{\text{Note}}$	40			
DC current gain	h _{FE2}	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -0.3 \text{ A}^{Note}$	40		200	
Collector saturation voltage	V _{CE(sat)}	$I_{C} = -3.0 \text{ A}, I_{B} = -0.3 \text{ A}^{\text{Note}}$			-0.6	V
Base saturation voltage	V _{BE(sat)}	$I_{\text{C}} = -3.0 \text{ A}, I_{\text{B}} = -0.3 \text{ A}^{\text{Note}}$			-1.5	V
Turn-on time	ton	Ic = -3.0 A, R _L = 17 Ω,			0.5	μs
Storage time	tstg	$I_{B1} = -I_{B2} = -0.3 \text{ A}, \text{ Vcc} \cong -50 \text{ V}$			2.5	μs
Fall time	t _f	Refer to the test circuit.			0.5	μs

Note Pulse test PW \leq 350 μ s, duty cycle \leq 2%

hfe CLASSIFICATION

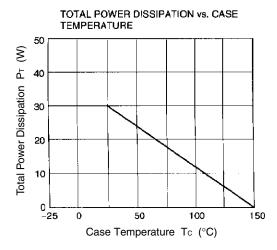
Marking	М	L	К
h _{FE2}	40 to 80	60 to 120	100 to 200

SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT

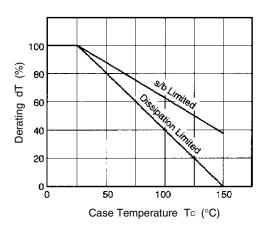




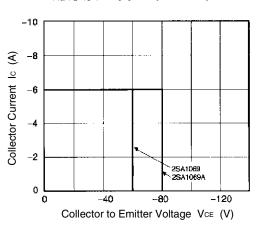
TYPICAL CHARACTERISTICS (TA = 25°C)



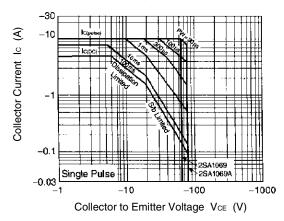
DERATING CURVE OF SAFE OPERATING AREA



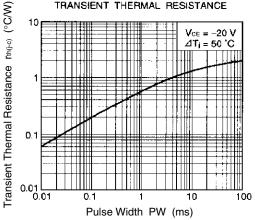
REVERSE BIAS SAFE OPERATING AREA



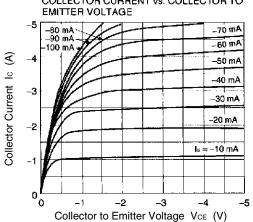
FORWARD BIAS SAFE OPERATING AREA



TRANSIENT THERMAL RESISTANCE

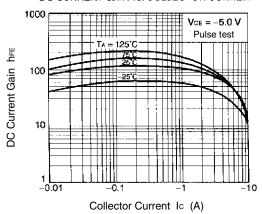


COLLECTOR CURRENT vs. COLLECTOR TO

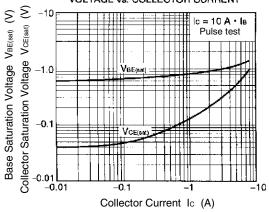


3

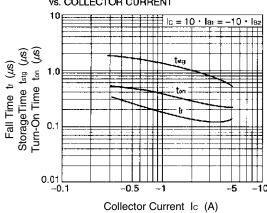
DC CURRENT GAIN vs. COLLECTOR CURRENT



COLLECTOR AND BASE SATURATION VOLTAGE vs. COLLECTOR CURRENT



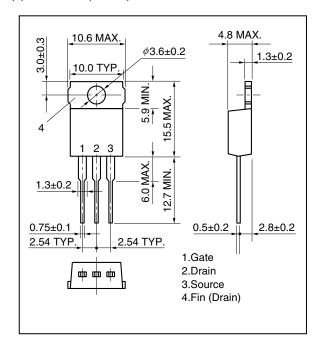
TURN ON TIME, STORAGE TIME AND FALL TIME vs. COLLECTOR CURRENT



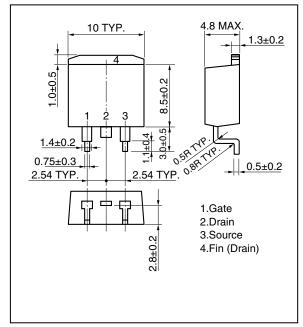


PACKAGE DRAWING (UNIT: mm)

(1) TO-220AB (MP-25)



<R> (2) TO-220SMD (MP-25Z) Note



Note This package is produced only in Japan.

5



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